

L Number	Hits	Search Text	DB	Time stamp
-	442	laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:21
-	95	laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 14:13
-	81	laser near semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:18
-	14	((laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)) not (laser near semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:18
-	347	(laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode) not (laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:21
-	59	((laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode) not (laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))) and ((multimode (multi adj mode)) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:38
-	0	20020064201.URPN.	USPAT	2002/08/20 15:23
-	2	"11068242"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:38
-	4	898346.URPN.	USPAT	2002/08/20 15:56
-	1	1999-134918.NRAN.	DERWENT	2002/08/20 15:56
-	1	3244116.URPN.	USPAT	2002/08/20 15:58
-	4	898346.URPN.	USPAT	2002/08/20 15:58
-	1224	372/\$.ccls. and ((multimode (multi adj mode)) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:12
-	589	(372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:08
-	394	((372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:09

578	{{(372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))) and laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:09
186	{{(372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
196	{{(372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj2 layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
35	{{(372/\$.ccls. and ((multimode (multi adj mode)) MMI) ) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj layer) and laser adj emission	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
22	372/\$.ccls. and (((multimode (multi adj mode)) adj interference) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:22
0	20010014109.URPN.	USPAT	2002/08/21 07:16
4	("4827482"   "5475776"   "5799119"   "5949931").PN.	USPAT	2002/08/21 07:17
1	6205163.URPN.	USPAT	2002/08/21 07:18
1612	(372/50).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:23
892	((372/50).CCLS.) and (waveguide wave adj guide)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:31
484	(385/28).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:01
0	("11 and semiconductor adj laser").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:02
56	((385/28).CCLS.) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:07
253	((385/28).CCLS.) and laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:07
197	((385/28).CCLS.) and laser) not ((385/28).CCLS.) and semiconductor adj laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:08
556	(385/17).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:08
49	((385/17).CCLS.) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:09
48	((385/17).CCLS.) and semiconductor adj laser) not ((385/28).CCLS.) and semiconductor adj laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:09